Vishay Semiconductors

Optocoupler, Phototriac Output, Non-Zero Crossing, 250 VDRM



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DESCRIPTION

The K3010P, K3010PG series consists of a photo-transistor optically coupled to a gallium arsenide infrared-emitting diode in a 6-pin plastic dual inline package

AGENCY APPROVALS

- UL1577, file no. E52744 system code H, double protection
- BSI: BS EN60065:2002 and IEC 60065:2001, certificate number 7955. An BS EN60950-1:2006 certificate number 7956
- DIN EN 60747-5-5
- CQC: GB8898-2001

FEATURES

- Isolation materials according to UL 94 V-0
- Special construction: therefore, extra low coupling capacity of typical 0.2 pF, high common mode rejection



COMPLIANT

- I_{FT} of 5 mA, 10 mA, and 15 mA
 Rated impulse voltage (transient overvoltage) V_{IOTM} = 8 kV_{peak}
- Isolation test voltage, 5300 V_{BMS}, t = 1 s
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

Circuits for safe protective separation against electrical shock according to safety class II (reinforced isolation):

- for appl. class I to IV at mains voltage \leq 300 V
- for appl. class I to IV at mains voltage ≤ 600 V according to DIN EN60747-5-5 (VDE0884), suitable for:
- Monitors
- Air conditioners
- Line switches
- Solid state relay
- Microwave



Note

• G = leadform 10.16 mm; G is not marked on the body.



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PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
INPUT				
Reverse voltage		V _R	5	V
Forward current		IF	80	mA
Forward surge current	$t_p \le 10 \ \mu s$	I _{FSM}	3	А
Power dissipation		P _{diss}	100	mW
Junction temperature		Tj	100	°C
OUTPUT				
Off state output terminal voltage		V _{DRM}	250	V
On state RMS current		I _{TRM}	100	mA
Peak surge current, non-repetitive	$t_p \le 10 \text{ ms}$	I _{TMS}	1.5	А
Power dissipation		P _{diss}	300	mW
Junction temperature		Tj	100	°C
COUPLER				
Isolation test voltage (RMS)	t = 1 s	V _{ISO}	5300	V _{RMS}
Total power dissipation		P _{tot}	350	mW
Storage temperature range		T _{stg}	- 55 to + 150	°C
Ambient temperature range		T _{amb}	- 55 to + 100	°C
Soldering temperature ⁽¹⁾	2 mm from case, t \leq 10 s	T _{sld}	260	°C

Notes

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
maximum ratings for extended periods of the time can adversely affect reliability.

⁽¹⁾ Refer to wave profile for soldering conditions for through hole devices (DIP) "Assembly Instructions" (<u>www.vishay.com/doc?80054</u>)

ELECTRICAL CHARACTERISTICS ($T_{amb} = 25 \text{ °C}$, unless otherwise specified)								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
INPUT								
Forward voltage	I _F = 50 mA		V _F		1.25	1.6	V	
Junction capacitance	V _R = 0, f = 1 MHz		Cj		50		pF	
OUTPUT								
Forward peak off-state voltage (repetitive)	I _{RDM} = 100 nA		V _{DRM} ⁽¹⁾	250			V	
Peak on-state voltage	I _{TM} = 100 mA		V _{TM}		1.5	3	V	
Critical rate of rise of off-state voltage	l _{FT} = 0, l _{FT} = 30 mA		dV/d _{tcr}		10		V/µs	
			dV/d _{tcrq}	0.1	0.2		V/µs	
COUPLER ⁽²⁾								
Collector emitter trigger current	V_{S} = 3 V, R _L = 150 Ω	K3010P	I _{FT}		8	15	mA	
		K3010PG	I _{FT}		8	15	mA	
		K3011P	I _{FT}		5	10	mA	
		K3011PG	I _{FT}		5	10	mA	
		K3012P	I _{FT}		2	5	mA	
		K3012PG	I _{FT}		2	5	mA	
Holding current	$I_F = 10 \text{ mA}, V_S \ge 3 \text{ V}$		I _H		100		μA	

Notes

• Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

⁽¹⁾ Test voltage must be applied within dV/dt ratings.

⁽²⁾ I_{FT} is defined as a minimum trigger current.



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Test condition: dV/dt_{cr} $V_{S} = 2/3 V_{DRM}$ (sine wave) $R_1 = 33 k\Omega$ dV/dt crq $V_{eff.} = 30 V$ (sine wave) $R_L = 2 k\Omega$

Fig. 1 - Test Circuit for dV/dt_{cr} and dV/dt_{cra}



dV/dt cr dV/dt crq

Highest value of the "rate of rise of off-state voltage" which does not cause any switching from the off state to the on state

Highest value of the "rate of rise of communicating voltage" which does not switch on the device again, after the voltage has decreased to zero and the trigger current is switched from I_{FT} to zero

Fig. 2







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SAFETY AND INSULATION RATINGS							
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT		
Climatic classification (according to IEC 68 part 1)			55/100/21				
Pollution degree (DIN VDE 0109)			2				
Comparative tracking index	CTI	175					
Peak transient overvoltage	V _{IOTM}			8000	V _{peak}		
Peak working insulation voltage	V _{IORM}			890	V _{peak}		
Partial discharge test voltage (method a, $V_{pd} = V_{IORM} \times 1.875$)	V _{pd}			1669	V _{peak}		
Isolation resistance at T_{amb} = 100 °C, V_{DC} = 500 V	R _{IO}	10 ¹¹			Ω		
Isolation resistance at $T_{amb} = 25 \text{ °C}$, $V_{DC} = 500 \text{ V}$	R _{IO}	10 ¹²			Ω		
Safety rating - power	P _{SO}			265	mW		
Safety rating - input current	I _{SI}			130	mA		
Safety rating - temperature	T _{SI}			150	°C		
Clearance distance (Standard DIP-6)		7			mm		
Creepage distance (Standard DIP-6)		7			mm		
Clearance distance (400 mil DIP-6)		8			mm		
Creepage distance (400 mil DIP-6)		8			mm		

Note

 According to DIN EN60747-5-5 (see figure 4). This optocoupler is suitable for safe electrical isolation only within the safety ratings. Compliance with the safety ratings shall be ensured by means of suitable protective circuits.



Fig. 4 - Safety Parameter Derating Diagram



Fig. 5 - Test Pulse Diagram for Sample Test according to DIN EN60747-5-5/DIN EN60747-; IEC 60747

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TYPICAL CHARACTERISTICS ($T_{amb} = 25$ °C, unless otherwise specified)



Fig. 6 - Total Power Dissipation vs. Ambient Temperature



Fig. 7 - Forward Current vs. Forward Voltage



Fig. 8 - Relative Threshold Forward Current vs. Ambient Temperature



Fig. 9 - Relative On-State vs. Ambient Temperature



Fig. 10 - Off-State Current vs. Ambient Temperature





Rev. 2.2, 01-Jun-12

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PACKAGE DIMENSIONS millimeters







G Series



Option 7





PACKAGE MARKING (example)



Notes

• The "G" of the 400 mil G leadform type is not marked on the body.

18450-12

• The VDE logo is only marked on option1 parts.

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